# 2.5V/3.3V 2:1:20 Differential HSTL/ECL/PECL Clock Driver

## Description

The NB100LVEP221 is a low skew 2:1:20 differential clock driver, designed with clock distribution in mind, accepting two clock sources into an input multiplexer. The two clock inputs are differential ECL/PECL; CLK1/ $\overline{\text{CLK1}}$  can also receive HSTL signal levels. The LVPECL input signals can be either differential configuration or single–ended (if the  $V_{BB}$  output is used).

The LVEP221 specifically guarantees low output-to-output skew. Optimal design, layout, and processing minimize skew within a device and from device to device.

To ensure tightest skew, both sides of differential outputs should be terminated identically into  $50~\Omega$  even if only one output is being used. If an output pair is unused, both outputs may be left open (unterminated) without affecting skew.

The NB100LVEP221, as with most other ECL devices, can be operated from a positive  $V_{\rm CC}$  supply in LVPECL mode. This allows the LVEP221 to be used for high performance clock distribution in +3.3 V or +2.5 V systems. In a PECL environment, series or Thevenin line terminations are typically used as they require no additional power supplies. For more information on PECL terminations, designers should refer to Application Note AND8020/D.

The  $V_{BB}$  pin, an internally generated voltage supply, is available to this device only. For single–ended LVPECL input conditions, the unused differential input is connected to  $V_{BB}$  as a switching reference voltage.  $V_{BB}$  may also rebias AC coupled inputs. When used, decouple  $V_{BB}$  and  $V_{CC}$  via a 0.01  $\mu F$  capacitor and limit current sourcing or sinking to 0.5 mA. When not used,  $V_{BB}$  should be left open.

Single–ended CLK input operation is limited to a  $V_{CC} \ge 3.0$  V in LVPECL mode, or  $V_{EE} \le -3.0$  V in NECL mode.

### **Features**

- 15 ps Typical Output-to-Output Skew
- 40 ps Typical Device-to-Device Skew
- Jitter Less than 2 ps RMS
- Maximum Frequency > 1.0 GHz Typical
- Thermally Enhanced 52-Lead LQFP and QFN
- V<sub>BB</sub> Output
- 540 ps Typical Propagation Delay
- LVPECL and HSTL Mode Operating Range: V<sub>CC</sub> = 2.375 V to 3.8 V with V<sub>EE</sub> = 0 V
- NECL Mode Operating Range:

 $V_{CC} = 0 \text{ V}$  with  $V_{EE} = -2.375 \text{ V}$  to -3.8 V

- $\bullet\;$  Q Output will Default Low with Inputs Open or at  $V_{EE}$
- Pin Compatible with Motorola MC100EP221
- These Devices are Pb-Free and are RoHS Compliant

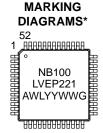


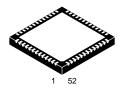
# ON Semiconductor®

www.onsemi.com

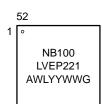


LQFP-52 FA SUFFIX CASE 848H





QFN-52 MN SUFFIX CASE 485M



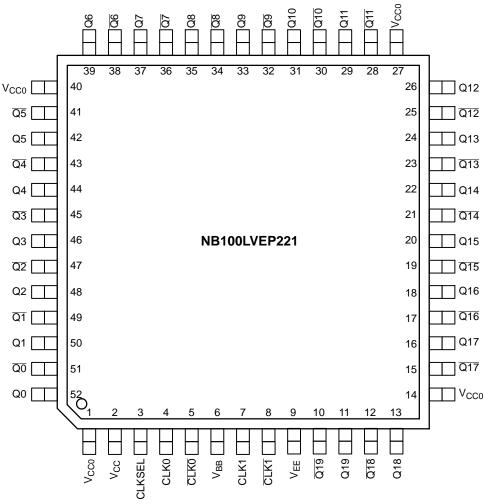
A = Assembly Location

WL = Wafer Lot
 YY = Year
 WW = Work Week
 G = Pb-Free Package

### ORDERING INFORMATION

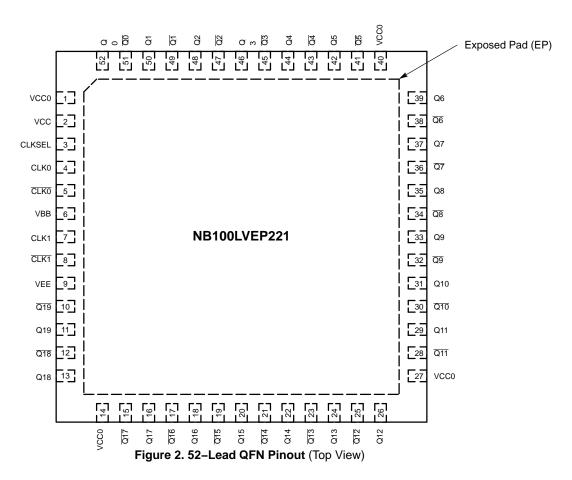
See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

<sup>\*</sup>For additional marking information, refer to Application Note AND8002/D.



All V<sub>CC</sub>, V<sub>CCO</sub>, and V<sub>EE</sub> pins must be externally connected to appropriate Power Supply to guarantee proper operation. The thermally conductive exposed pad on package bottom (see package case drawing) must be attached to a heat–sinking conduit, capable of transferring 1.2 Watts. This exposed pad is electrically connected to V<sub>EE</sub> internally.

Figure 1. 52-Lead LQFP Pinout (Top View)



**Table 1. PIN DESCRIPTION** 

PIN	FUNCTION			
CLK0*, CLK0**	ECL/PECL Differential Inputs			
CLK1*, CLK1**	ECL/PECL or HSTL Differential Inputs			
Q0:19, Q0:19	ECL/PECL Differential Outputs			
CLK_SEL*	ECL/PECL Active Clock Select Input			
V <sub>BB</sub>	Reference Voltage Output			
V <sub>CC</sub> /V <sub>CCO</sub>	Positive Supply			
V <sub>EE***</sub>	Negative Supply			

- \* Pins will default LOW when left open.
- \*\* Pins will default HIGH when left open.
- \*\*\* The thermally conductive exposed pad on the bottom of the package is electrically connected to V<sub>EE</sub> internally.

**Table 2. FUNCTION TABLE** 

CLK_SEL	Active Input
L	CLK0, <u>CLK0</u>
H	CLK1, <u>CLK1</u>

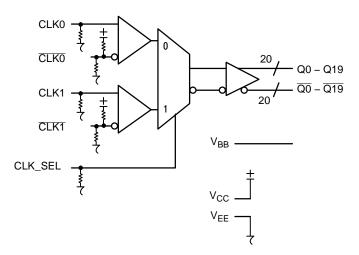


Figure 3. Logic Diagram

**Table 3. ATTRIBUTES** 

Character	stics	Value
Internal Input Pulldown Resistor	75 kΩ	
Internal Input Pullup Resistor	37.5 kΩ	
ESD Protection	> 2 kV > 200 V > 2 kV	
Moisture Sensitivity, Indefinite Tim	e Out of Drypack (Note 1)	Pb-Free Pkg
	LQFP-52 QFN-52	Level 3 Level 2
Flammability Rating	UL 94 V-0 @ 0.125 in	
Transistor Count	533 Devices	
Meets or exceeds JEDEC Spec E	IA/JESD78 IC Latchup Test	

<sup>1.</sup> For additional information, refer to Application Note AND8003/D.

**Table 4. MAXIMUM RATINGS** 

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	PECL Mode Power Supply	V <sub>EE</sub> = 0 V		6	V
V <sub>EE</sub>	NECL Mode Power Supply	V <sub>CC</sub> = 0 V		-6	V
V <sub>I</sub>	PECL Mode Input Voltage NECL Mode Input Voltage	V <sub>EE</sub> = 0 V V <sub>CC</sub> = 0 V	$\begin{array}{c} V_I \leq V_{CC} \\ V_I \geq V_{EE} \end{array}$	6 -6	V V
l <sub>out</sub>	Output Current	Continuous Surge		50 100	mA mA
I <sub>BB</sub>	V <sub>BB</sub> Sink/Source			± 0.5	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction–to–Ambient) (See Application Information)	0 lfpm 500 lfpm	LQFP-52 LQFP-52	35.6 30	°C/W °C/W
θЈС	Thermal Resistance (Junction–to–Case) (See Application Information)	0 lfpm 500 lfpm	LQFP-52 LQFP-52	3.2 6.4	°C/W
$\theta_{JA}$	Thermal Resistance (Junction–to–Ambient) (Note )	0 lfpm 500 lfpm	QFN-52 QFN-52	25 19.6	°C/W
θЈС	Thermal Resistance (Junction-to-Case) (Note )	2S2P	QFN-52	21	°C/W
T <sub>sol</sub>	Wave Solder Pb Pb-Free			265 265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 5. LVPECL DC CHARACTERISTICS V<sub>CC</sub> = 2.5 V; V<sub>EE</sub> = 0 V (Note 2)

			-40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current	100	125	150	104	130	156	116	145	174	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 3)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3)	555	680	900	555	680	900	555	680	900	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended) (Note 4)			1620	1335		1620	1275		1620	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended) (Note 4)	555		900	555		900	555		900	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 5)  CLK0/CLK0  CLK1/CLK1			2.5 1.6	1.2 0.3		2.5 1.6	1.2 0.3		2.5 1.6	V V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

- 2. Input and output parameters vary 1:1 with  $V_{CC}$ .  $V_{EE}$  can vary + 0.125 V to -1.3 V.
- 3. All outputs loaded with 50  $\Omega$  to V<sub>CC</sub> 2.0 V.
- 4. Do not use  $V_{BB}$  at  $V_{CC}$  < 3.0 V.
- 5. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal.

Table 6. LVPECL DC CHARACTERISTICS  $V_{CC} = 3.3 \text{ V}$ ;  $V_{EE} = 0 \text{ V}$  (Note 6)

			-40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current	100	125	150	104	130	156	116	145	174	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 7)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V <sub>OL</sub>	Output LOW Voltage (Note 7)	1355	1480	1700	1355	1480	1700	1355	1480	1700	mV
V <sub>IH</sub>	Input HIGH Voltage (Single–Ended)			2420	2135		2420	2135		2420	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)			1700	1355		1700	1355		1700	mV
$V_{BB}$	Output Reference Voltage (Note 8)	1775	1875	1975	1775	1875	1975	1775	1875	1975	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 9)  CLK0/CLK0  CLK1/CLK1			3.3 1.6	1.2 0.3		3.3 1.6	1.2 0.3		3.3 1.6	V V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

- 6. Input and output parameters vary 1:1 with V<sub>CC</sub>. V<sub>EE</sub> can vary + 0.925 V to –0.5 V. 7. All outputs loaded with 50  $\Omega$  to V<sub>CC</sub> 2.0 V.
- 8. Single–ended input operation is limited  $V_{CC} \ge 3.0 \text{ V}$  in LVPECL mode.
- 9. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal.

Table 7. LVNECL DC CHARACTERISTICS  $V_{CC} = 0 \text{ V}$ ,  $V_{EE} = -2.375 \text{ V}$  to -3.8 V (Note 10)

			-40°C			25°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current	100	125	150	104	130	156	116	145	174	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 11)	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV
V <sub>OL</sub>	Output LOW Voltage (Note 11)	-1945	-1820	-1600	-1945	-1820	-1600	-1945	-1820	-1600	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)			-880	-1165		-880	-1165		-880	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	-1945		-1600	-1945		-1600	-1945		-1600	mV
V <sub>BB</sub>	Output Reference Voltage (Note 12)	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 13) CLK0/CLK0 CLK1/CLK1		+ 1.2 + 0.3	0.0 -0.9		+ 1.2 + 0.3	0.0 -0.9		+ 1.2 + 0.3	0.0 -0.9	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Table 8. HSTL DC CHARACTERISTICS  $V_{CC} = 3.3 \text{ V}$ ;  $V_{EE} = 0 \text{ V}$ 

		0°C		25°C							
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V <sub>IH</sub>	Input HIGH Voltage CLK1/CLK1	V <sub>x</sub> +100		1600	V <sub>x</sub> +100		1600	V <sub>x</sub> +100		1600	mV
V <sub>IL</sub>	Input LOW Voltage CLK1/CLK1	-300		V <sub>x</sub> -100	-300		V <sub>x</sub> -100	-300		V <sub>x</sub> -100	mV
V <sub>X</sub>	Differential Configuration Cross Point Voltage	680		900	680		900	680		900	mV
I <sub>IH</sub>	Input HIGH Current	-150		150	-150		150	-150		150	μΑ
I <sub>IL</sub>	Input LOW Current CLK1	-150 -250			-150 -250			-150 -250			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

<sup>10.</sup> Input and output parameters vary 1:1 with V<sub>CC</sub>.
11. All outputs loaded with 50 Ω to V<sub>CC</sub>-2.0 V.
12. Single–ended input operation is limited V<sub>EE</sub> ≤ -3.0V in NECL mode.
13. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal.

			-40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V <sub>Opp</sub>	$\begin{array}{ll} \text{Differential Output Voltage} \\ \text{(Figure 4)} & f_{\text{out}} < 50 \text{ MHz} \\ f_{\text{out}} < 0.8 \text{ GHz} \\ f_{\text{out}} < 1.0 \text{ GHz} \end{array}$	550 550 500	700 700 700		600 550 500	700 700 700		600 500 400	700 700 600		mV mV mV
t <sub>PLH</sub> /t <sub>PHL</sub>	Propagation Delay (Differential Configuration) CLK0-Qx CLK1-Qx		540 590	600 640		540 590	660 710		540 590	750 800	ps ps
t <sub>skew</sub>	Within–Device Skew (Note 15) Device–to–Device Skew (Note 16)		15 40	50 200		15 40	50 200		15 40	50 200	ps ps
t <sub>JITTER</sub>	Random Clock Jitter (RMS) (Figure 4)		1	2		1	2		1	2	ps
V <sub>PP</sub>	Input Swing (Differential Configuration) (Note 17) (Figure 5) CLK0 CLK1 HSTL	400 300	800 800	1200 1000	400 300	800 800	1200 1000	400 300	800 800	1200 1000	mV mV
DCO	Output Duty Cycle	49.5	50	50.5	49.5	50	50.5	49.5	50	50.5	%
t <sub>r</sub> /t <sub>f</sub>	Output Rise/Fall Time (20%–80%)	100	200	300	100	200	300	150	250	350	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

<sup>14.</sup> Measured with 750 mV source (LVPECL) or 1 V (HSTL) source, 50% duty cycle clock source. All outputs loaded with 50  $\Omega$  to V<sub>CC</sub>-2 V.

<sup>15.</sup> Skew is measured between outputs under identical transitions and conditions on any one device.

<sup>16.</sup> Device–to–Device skew for identical transitions, outputs and  $V_{\hbox{\footnotesize{CC}}}$  levels.

<sup>17.</sup>V<sub>PP</sub> is the differential configuration input voltage swing required to maintain AC characteristics.

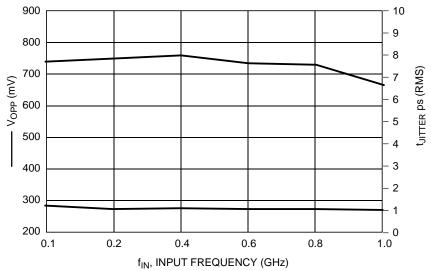


Figure 4. Output Voltage (V<sub>OPP</sub>)/Jitter versus Input Frequency (V<sub>CC</sub> - V<sub>EE</sub> = 3.3 V @ 25°C)

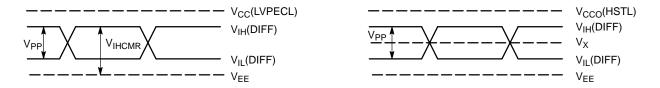


Figure 5. LVPECL Differential Input Levels

Figure 6. HSTL Differential Input Levels

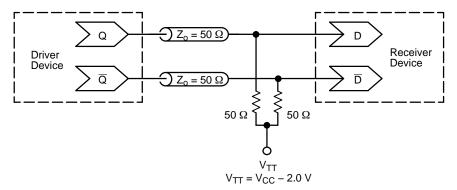


Figure 7. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

### **APPLICATIONS INFORMATION**

# Using the thermally enhanced package of the NB100LVEP221

The NB100LVEP221 uses a thermally enhanced 52-lead LQFP package. The package is molded so that a portion of the leadframe is exposed at the surface of the package bottom side. This exposed metal pad will provide the low thermal impedance that supports the power consumption of the NB100LVEP221 high-speed bipolar integrated circuit and will ease the power management task for the system design. In multilayer board designs, a thermal land pattern on the printed circuit board and thermal vias are recommended to maximize both the removal of heat from the package and electrical performance of NB100LVEP221. The size of the land pattern can be larger, smaller, or even take on a different shape than the exposed pad on the package. However, the solderable area should be at least the same size and shape as the exposed pad on the package. Direct soldering of the exposed pad to the thermal land will provide an efficient thermal conduit. The thermal vias will connect the exposed pad of the package to internal copper planes of the board. The number of vias, spacing, via diameters and land pattern design depend on the application and the amount of heat to be removed from the package.

Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern.

The recommended thermal land design for NB100LVEP221 applications on multi-layer boards comprises a 4 X 4 thermal via array using a 1.2 mm pitch as shown in Figure 8 providing an efficient heat removal path.

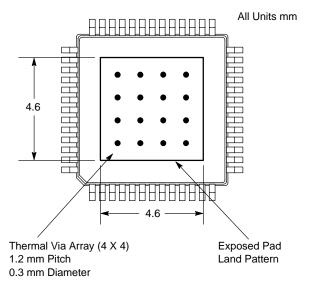


Figure 8. Recommended Thermal Land Pattern

The via diameter should be approximately 0.3 mm with 1 oz. copper via barrel plating. Solder wicking inside the via may result in voiding during the solder process and must be avoided. If the copper plating does not plug the vias, stencil print solder paste onto the printed circuit pad. This will

supply enough solder paste to fill those vias and not starve the solder joints. The attachment process for the exposed pad package is equivalent to standard surface mount packages. Figure 9, "Recommended solder mask openings", shows a recommended solder mask opening with respect to a 4 X 4 thermal via array. Because a large solder mask opening may result in a poor rework release, the opening should be subdivided as shown in Figure 9. For the nominal package standoff of 0.1 mm, a stencil thickness of 5 to 8 mils should be considered.

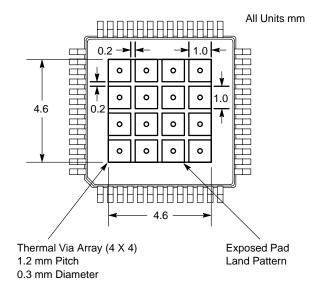


Figure 9. Recommended Solder Mask Openings

Proper thermal management is critical for reliable system operation. This is especially true for high–fanout and high output drive capability products.

For thermal system analysis and junction temperature calculation, the thermal resistance parameters of the package are provided:

Table 10. Thermal Resistance \*

lfpm	θJA °C/W	θJC °C/W
0	35.6	3.2
100	32.8	4.9
500	30.0	6.4

\* Junction to ambient and Junction to board, four-conductor layer test board (2S2P) per JESD 51-8

These recommendations are to be used as a guideline, only. It is therefore recommended that users employ sufficient thermal modeling analysis to assist in applying the general recommendations to their particular application to assure adequate thermal performance. The exposed pad of the NB100LVEP221 package  $\underline{is}$  electrically shorted to the substrate of the integrated circuit and  $V_{EE}$ . The thermal land should be electrically connected to  $V_{EE}$ .

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>				
NB100LVEP221FAG	LQFP-52 (Pb-Free)	160 Units / Tray				
NB100LVEP221FARG	LQFP-52 (Pb-Free)	1500 / Tape & Reel				
NB100LVEP221MNG	QFN-52 (Pb-Free)	260 Units / Tray				
NB100LVEP221MNR2G	QFN-52 (Pb-Free)	2000 / Tape & Reel				

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **Resource Reference of Application Notes**

AN1405/D – ECL Clock Distribution Techniques
 AN1406/D – Designing with PECL (ECL at +5.0 V)
 AN1503/D – ECLinPS™ I/O SPiCE Modeling Kit
 AN1504/D – Metastability and the ECLinPS Family
 AN1568/D – Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide
AND8001/D - Odd Number Counters Design

**AND8002/D** – Marking and Date Codes

AND8020/D - Termination of ECL Logic Devices

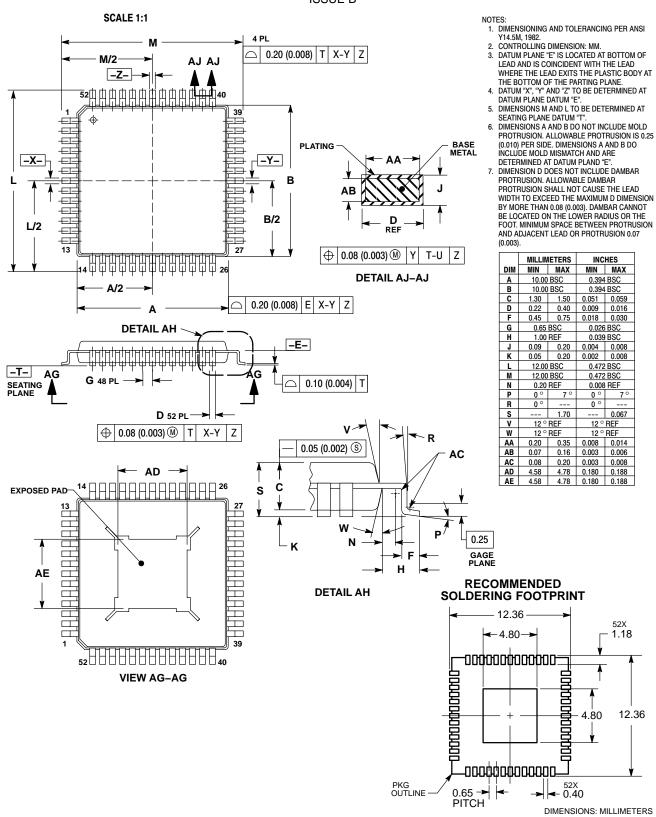
AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

### PACKAGE DIMENSIONS

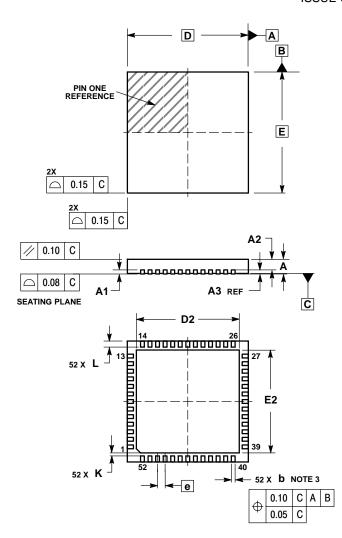
#### **LQFP 52 EXPOSED PAD**

CASE 848H ISSUE B



### PACKAGE DIMENSIONS

### QFN52 8x8, 0.5P CASE 485M **ISSUE C**



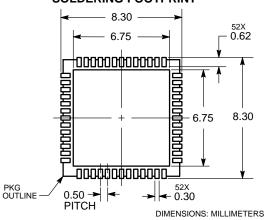
#### NOTES

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS
  DIMENSION & APPLIES TO PLATED TERMINAL
  AND IS MEASURED BETWEEN 0.25 AND 0.30
- MM FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED

PAD AS WELL AS THE TERMINALS.

	MILLIMETERS							
DIM	MIN	MAX						
Α	0.80	1.00						
A1	0.00	0.05						
A2	0.60	0.80						
A3	0.20	REF						
b	0.18	0.30						
D	8.00	BSC						
D2	6.50	6.80						
E	8.00	BSC						
E2	6.50	6.80						
е	0.50	BSC						
K	0.20							
L	0.30	0.50						

### RECOMMENDED SOLDERING FOOTPRINT



ON Semiconductor and the unarregistered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## **PUBLICATION ORDERING INFORMATION**

### LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative